



SN74LVC1G38 (LX)

Single 2-input Nand Gate (Open-drain)

Product Specification

Specification Revision History:

Version	Date	Description
2017-05-A1	2017-05	New
2023-04-B1	2023-04	Update the template



Contents

1、General Description.....	3
2、Block Diagram And Pin Description	4
2.1、Block Diagram	4
2.2、Pin Configurations.....	4
2.3、Pin Description.....	4
2.4、Function Table.....	5
3、Electrical Parameter	5
3.1、Absolute Maximum Ratings.....	5
3.2、Recommended Operating Conditions	5
3.3、Electrical Characteristics.....	6
3.3.1、DC Characteristics 1	6
3.3.2、DC Characteristics 2.....	7
3.3.3、AC Characteristics 1.....	8
3.3.4、AC Characteristics 2.....	8
4、Testing Circuit	8
4.1、AC Testing Circuit	8
4.2、AC Testing Waveforms.....	9
4.3、Measurement Points	9
4.4、Test Data	9
5、Package Information.....	10
5.1、SOT23-5.....	10
5.2、SOT353.....	11
6、Statements.....	12
6.1、The name and content of Hazardous substances or Elements in the product.....	12



1、General Description

The SN74LVC1G38 provides a 2-input NAND function.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of this device as translator in a mixed 3.3V and 5V environment.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- 5V tolerant outputs for interfacing with 5V logic
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Open drain outputs
- Specified from -40°C to $+125^{\circ}\text{C}$
- Packaging information: SOT-23-5/SOT-353

Ordering Information:

Reel packing specifications:

Part number	Packaging form	Marking code	Reel quantity	Boxed reel quantity	Notes
SN74LVC1G38DB (LX)	SOT-23-5	AIXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.9mm×1.6mm Pin spacing: 0.95mm
SN74LVC1G38DC (LX)	SOT-353	AIXX	3000 PCS/reel	30000 PCS/box	Dimensions of plastic enclosure: 2.1mm×1.3mm Pin spacing: 0.65mm

Note 1: “XX” refers to variable content, meaning year and package batch serial number.

Note 2: If the physical information is inconsistent with the ordering information, please refer to the actual product.

2、Block Diagram And Pin Description

2.1、Block Diagram

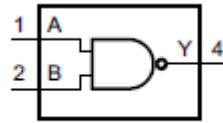


Figure 1. Logic symbol



Figure 2. IEC logic symbol

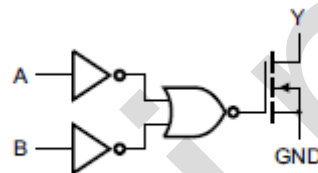
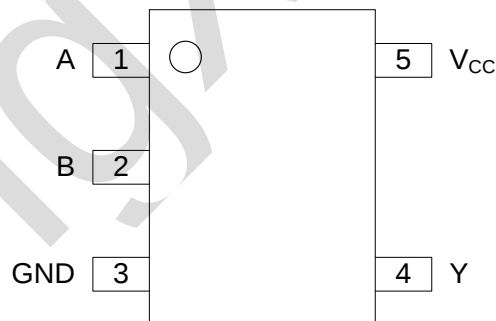


Figure 3. Logic diagram

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	A	data input
2	B	data input
3	GND	ground (0V)
4	Y	data output
5	V _{CC}	supply voltage



2.4、Function Table

Input		Output
A	B	Y
L	L	Z
L	H	Z
H	L	Z
H	H	L

Note: H=HIGH voltage level; L=LOW voltage level; Z=high-impedance OFF state.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input voltage	V_I	-	-0.5	+6.5	V
output voltage	V_O	Active mode	-0.5	+6.5	V
		Power-down mode	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output current	I_O	$V_O = 0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
storage temperature	T_{stg}	-	-65	+150	°C
total power dissipation	P_{tot}	-	-	300	mW
soldering temperature	T_L	10s	260		°C

Note: When $V_{CC}=0V$ (Power-down mode), the output voltage can be 5.5V in normal operation.

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	5.5	V
		Disable mode; $V_{CC}=1.65V$ to $5.5V$	0	-	5.5	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+125	°C



3.3、Electrical Characteristics

3.3.1、DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65× V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7× V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35× V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3× V _{CC}	V
LOW-level output voltage	V _{OL}	V _I = V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.10	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.45	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.30	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.40	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.55	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.55	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	-	±1	uA
OFF-state output current	I _{OZ}	V _I =V _{IH} or V _{IL} ; V _O =V _{CC} or GND; V _{CC} =5.5V		-	-	±2	uA
power-off leakage current	I _{OFF}	V _I or V _O =5.5V; V _{CC} =0V		-	-	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; I _O =0A; V _{CC} =1.65V to 5.5V		-	-	4	uA
additional supply current	ΔI _{CC}	per pin; V _I =V _{CC} -0.6V; I _O =0A; V _{CC} =2.3V to 5.5V		-	-	500	uA
input capacitance	C _I	-		-	2.5	-	pF

Note: All typical values are measured at $V_{CC}=3.3\text{V}$ and $T_{amb}=25^{\circ}\text{C}$.



3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V _{IH}	V _{CC} =1.65V to 1.95V		0.65× V _{CC}	-	-	V
		V _{CC} =2.3V to 2.7V		1.7	-	-	V
		V _{CC} =2.7V to 3.6V		2.0	-	-	V
		V _{CC} =4.5V to 5.5V		0.7× V _{CC}	-	-	V
LOW-level input voltage	V _{IL}	V _{CC} =1.65V to 1.95V		-	-	0.35× V _{CC}	V
		V _{CC} =2.3V to 2.7V		-	-	0.7	V
		V _{CC} =2.7V to 3.6V		-	-	0.8	V
		V _{CC} =4.5V to 5.5V		-	-	0.3× V _{CC}	V
LOW-level output voltage	V _{OL}	V _I = V _{IH} or V _{IL}	I _O =100uA; V _{CC} =1.65V to 5.5V	-	-	0.10	V
			I _O =4mA; V _{CC} =1.65V	-	-	0.70	V
			I _O =8mA; V _{CC} =2.3V	-	-	0.45	V
			I _O =12mA; V _{CC} =2.7V	-	-	0.60	V
			I _O =24mA; V _{CC} =3.0V	-	-	0.80	V
			I _O =32mA; V _{CC} =4.5V	-	-	0.80	V
input leakage current	I _I	V _I =5.5V or GND; V _{CC} =0V to 5.5V		-	-	±1	uA
OFF-state output current	I _{OZ}	V _I =V _{IH} or V _{IL} ; V _O =V _{CC} or GND; V _{CC} =5.5V		-	-	±2	uA
power-off leakage current	I _{OFF}	V _I or V _O =5.5V; V _{CC} =0V		-	-	±2	uA
supply current	I _{CC}	V _I =5.5V or GND; I _O =0A; V _{CC} =1.65V to 5.5V		-	-	4	uA
additional supply current	ΔI _{CC}	per pin; V _I =V _{CC} -0.6V; I _O =0A; V _{CC} =2.3V to 5.5V		-	-	500	uA



3.3.3、AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ. ^[1]	Max.	Unit
A, B to Y propagation delay	t_{PHL}, t_{PLH}	see Figure 5	$V_{CC}=1.65\text{V to }1.95\text{V}$	-	10.5	ns
			$V_{CC}=2.3\text{V to }2.7\text{V}$	-	6.3	ns
			$V_{CC}=2.7\text{V}$	-	8.8	ns
			$V_{CC}=3.0\text{V to }3.6\text{V}$	-	8.1	ns
			$V_{CC}=4.5\text{V to }5.5\text{V}$	-	5.3	ns

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}\text{C}$ and $V_{CC}=1.8\text{V}, 2.5\text{V}, 2.7\text{V}, 3.3\text{V}$ and 5.0V respectively.

3.3.4、AC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
A, B to Y propagation delay	t_{PHL}, t_{PLH}	see Figure 5	$V_{CC}=1.65\text{V to }1.95\text{V}$	-	19.7	ns
			$V_{CC}=2.3\text{V to }2.7\text{V}$	-	11.8	ns
			$V_{CC}=2.7\text{V}$	-	17.1	ns
			$V_{CC}=3.0\text{V to }3.6\text{V}$	-	15.3	ns
			$V_{CC}=4.5\text{V to }5.5\text{V}$	-	9.9	ns

4、Testing Circuit

4.1、AC Testing Circuit

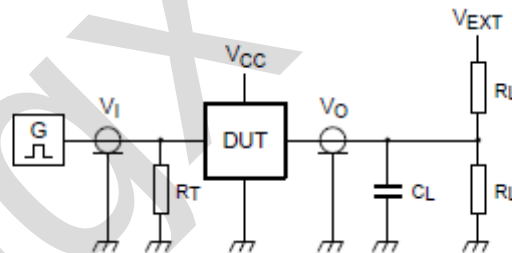


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.



4.2、AC Testing Waveforms

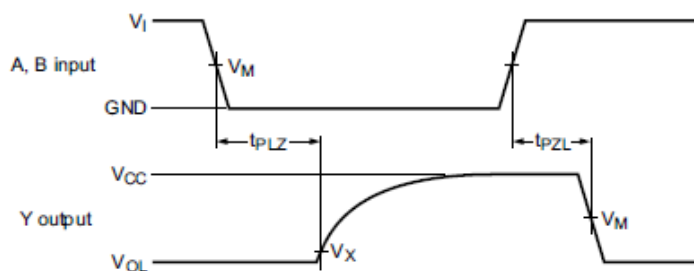


Figure 5. The input A, B to output Y propagation delays

4.3、Measurement Points

Supply voltage	Input	Output	
V_{CC}	V_M	V_M	V_X
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15V$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15V$
2.7V	1.5V	1.5V	$V_{OL} + 0.3V$
3.0V to 3.6V	1.5V	1.5V	$V_{OL} + 0.3V$
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.3V$

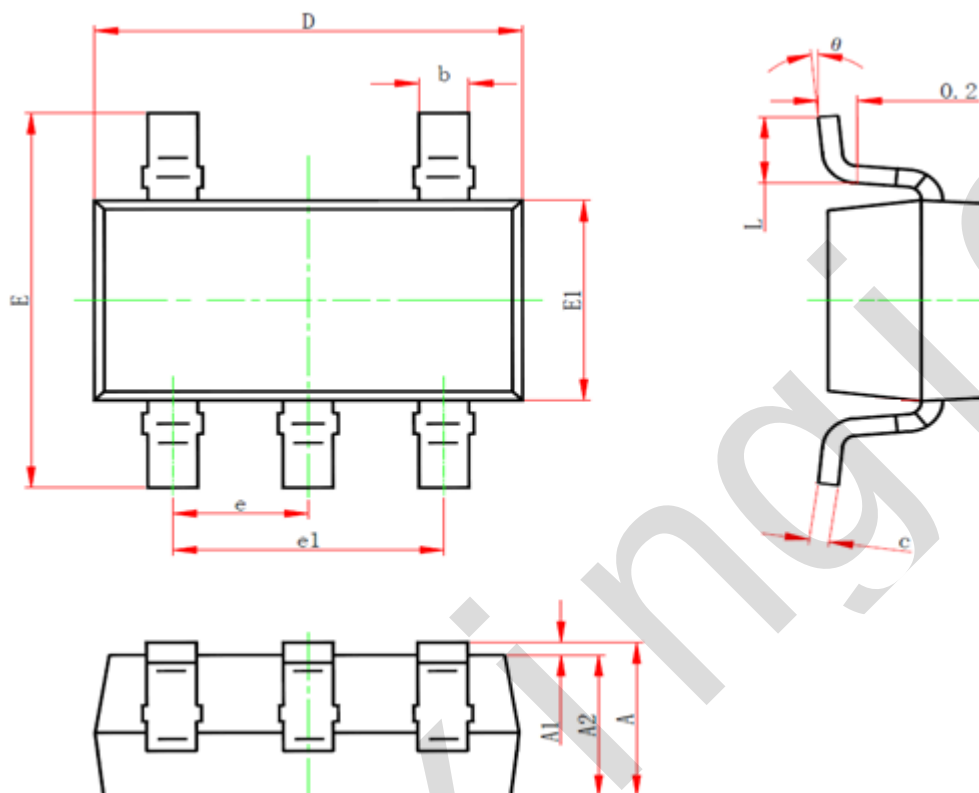
4.4、Test Data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{pZL}, t_{pLZ}
1.65V to 1.95V	V_{CC}	$\leq 3ns$	30pF	1k Ω	V_{CC}
2.3V to 2.7V	V_{CC}	$\leq 3ns$	30pF	500 Ω	V_{CC}
2.7V	2.7V	$\leq 3ns$	50pF	500 Ω	V_{CC}
3.0V to 3.6V	2.7V	$\leq 3ns$	50pF	500 Ω	V_{CC}
4.5V to 5.5V	V_{CC}	$\leq 3ns$	50pF	500 Ω	V_{CC}



5、Package Information

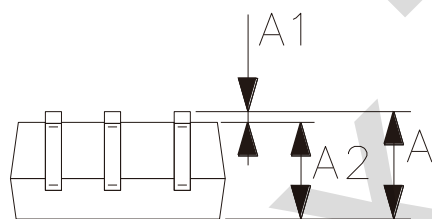
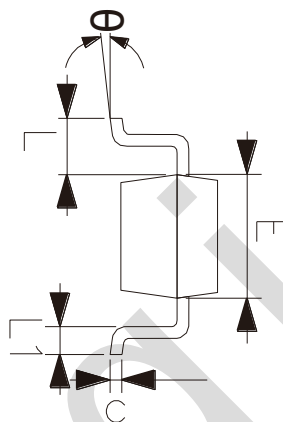
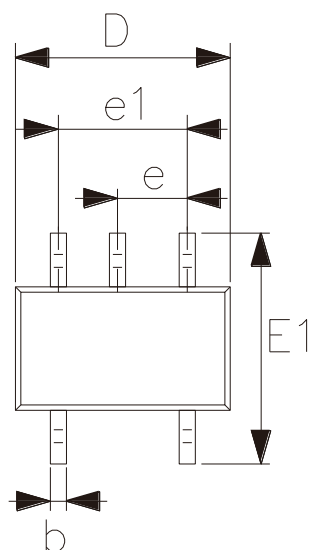
5.1、SOT23-5



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.26
A1	0.00	0.12
A2	1.00	1.20
b	0.30	0.50
c	0.10	0.20
D	2.82	3.02
E	2.60	3.00
E1	1.50	1.70
e	0.95	
e1	1.80	2.00
L	0.30	0.60
θ	0°	8°



5.2、SOT353



Symbol	Dimensions (mm)	
	Min.	Max.
A	0.90	1.10
A1	0.00	0.10
A2	0.90	1.00
b	0.15	0.35
c	0.11	0.175
D	2.00	2.20
E	1.15	1.35
E1	2.15	2.45
e	0.65	
e1	1.20	1.40
L	0.525	
L1	0.26	0.46
θ	0°	8°



6、Statements

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									